

CD74HCT356

High-Speed CMOS Logic

SCLS459A - June 2001 - Revised May 2003

Features

- Edge-Triggered Data Flip-Flops
 - Transparent Select Latches
- Buffered Inputs
- 3-State Complementary Outputs
- Bus Line Driving Capability
- Typical Propagation Delay: V_{CC} = 5V, C_L = 15pF, T_A = 25^oC
 - Clock to Output = 22ns
- Fanout (Over Temperature Range)
 - Standard Outputs 10 LSTTL Loads
- Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- 4.5V to 5.5V Operation
- Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
- CMOS Input Compatibility, $I_I \leq 1\mu A$ at V_{OL} , V_{OH}

Pinout



Description

The CD74HCT356 consists of data selectors/multiplexers that select one of eight sources. The data select bits (S0, S1, and S2) are stored in transparent latches that are enabled by a low latch enable input (LE).

8-Input Multiplexer/Register, Three-State

The data is stored in edge-triggered flip-flops that are triggered by a low-to-high clock transition.

In both types the 3-state outputs are controlled by three output-enable inputs ($\overline{OE1}$, $\overline{OE2}$, and OE3).

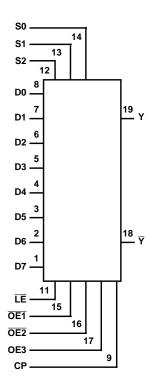
Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD74HCT356E	-55 to 125	20 Ld PDIP
CD74HCT356M96	-55 to 125	20 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

		CD74HCT350 PDIP or SOIO TOP VIEW	-	
D7	1		20	v _{cc}
D6	2		19	Y
D5	3		18	Y
D4	4		17	OE3
D3	5		16	OE2
D2	6		15	OE1
D1	7		14	S0
D0	8		13	S 1
СР	9		12	S2
GND	10		11	LE

Functional Diagram



TRUTH TABLE

				INPUTS			
OUTPUTS	.ES	TPUT ENABL	OU	CLOCK	1)	LECT (NOTE	SE
Ϋ́Υ Υ	OE3	OE2	OE1	СР	S0	S1	S2
Z Z	Х	Х	Н	Х	Х	Х	Х
z z	х	Н	Х	Х	Х	Х	Х
Z Z	L	Х	Х	Х	Х	Х	Х
D0 D0	Н	L	L	↑	L	L	L
D0 _n D0 _r	Н	L	L	H or L	L	L	L
D1 D1	Н	L	L	↑	Н	L	L
D1 _n D1 _r	Н	L	L	H or L	Н	L	L
D2 D2	Н	L	L	↑	L	Н	L
D2 _n D2 _r	Н	L	L	H or L	L	Н	L
D3 D3	Н	L	L	↑	Н	Н	L
D3 _n D3 _r	Н	L	L	H or L	Н	Н	L
D4 D4	Н	L	L	↑	L	L	н
D4 _n D4 _r	Н	L	L	H or L	L	L	Н
D5 D5	Н	L	L	↑	Н	L	Н
D5 _n D5 _r	н	L	L	H or L	Н	L	Н
D6 D6	Н	L	L	↑	L	Н	Н
D6 _n D6 _r	Н	L	L	H or L	L	Н	Н

CD74HCT356

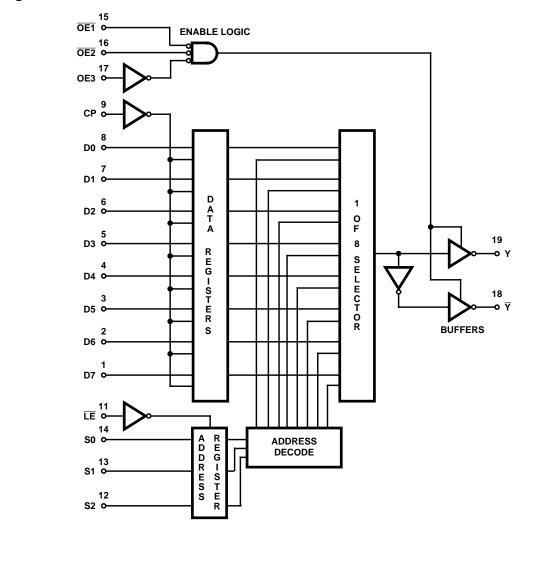
TRUTH TABLE (Continued)

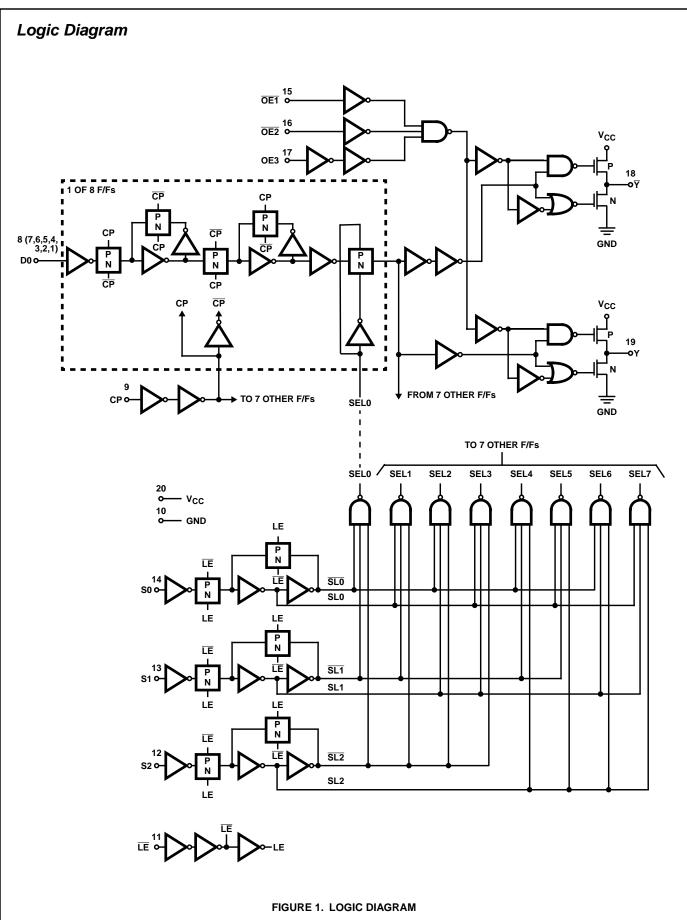
	INPUTS									
SE	LECT (NOTE	1)	CLOCK	CLOCK OUTPUT ENABLES				OUTPUTS		
S2	S1	S0	СР	OE1	OE2	OE3	Ŧ	Y		
н	Н	Н	↑	L	L	Н	D7	D7		
н	н	Н	H or L	L	L	н	D7 _n	D7 _n		

H = High Voltage Level (Steady State); L = Low Voltage Level (Steady State); \uparrow = Transition from Low to High Level; X = Don't Care; Z = High-Impedance State (Off State); D0_n...D7_n = the level of steady-state inputs D0 through D7, respectively, before the most recent low-to-high transition of data control. NOTE:

1. This column shows the input address setup with $\overline{\text{LE}}$ low.

Block Diagram





Absolute Maximum Ratings

DC Supply Voltage, V _{CC}
For $V_{l} < -0.5V$ or $V_{l} > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ±20mA
DC Drain Current, per Output, I _O
For -0.5V < V _O < V _{CC} + 0.5V±35mA
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC} ±50mA
Operating Conditions

Thermal Resistance (Typical, Note 2)	θ _{JA} (^o C/W)
E (PDIP) Package	. 69
M (SOIC) Package	. 58
Maximum Junction Temperature	
Maximum Storage Temperature Range	
Maximum Lead Temperature (Soldering 10s)	З00 ⁰ С
(SOIC - Lead Tips Only)	

Operating Conditions

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TEST CONDITIONS			25 ⁰ C			-40 ⁰ C TO 85 ⁰ C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} to GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA
3-State Leakage Current	I _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5	-	±10	μA

NOTE:

3. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Input Loading Table

UNIT LOADS
0.50
0.70
0.80
0.25
0.25
0.60

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g., 360µA max at 25^oC.

Prerequisite For Switching Specifications

		TEST V _{CC}			25 ⁰ C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
CP Pulse Width	t _{PLH} , t _{PHL}	-	4.5	16	20	-	25	-	30	-	ns
LE Pulse Width	t _{PLH} , t _{PHL}	-	4.5	16	20	-	25	-	30	-	ns
Setup Times $Dn \to \overline{E}$	ts∪	-	4.5	5	7	-	9	-	11	-	ns
Setup Times Sn $\rightarrow \overline{\text{LE}}$	ts∪	-	4.5	5	7	-	9	-	11	-	ns
Hold Times $\text{Dn}\to\overline{\text{E}}$	t _H	-	4.5	9	9	-	11	-	14	-	ns
Hold Times Sn $\rightarrow \overline{\text{LE}}$	t _H	-	4.5	12	12	-	15	-	18	-	ns

		TEST		25 ⁰ C		-40°C TO 85°C	-55 ⁰ C TO 125 ⁰ C	
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	TYP	МАХ	МАХ	MAX	
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	51	64	77	ns
$CP \rightarrow Y, \overline{Y}$		C _L = 15pF	5	22	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	59	74	89	ns
$Sn \rightarrow Y, \overline{Y}$		C _L = 15pF	5	25	-	-	-	ns
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	63	79	94	ns
$\overline{LE} \to Y, \overline{Y}$		C _L = 15pF	5	25	-	-	-	ns
Output Disabling Time	t _{PLZ} , t _{PHZ}	C _L = 50pF	4.5	-	33	41	50	ns
	t _{PLZ}	C _L = 15pF	5	13	-	-	-	ns
	t _{PHZ}	C _L = 15pF	5	15	-	-	-	ns
Output Enabling Time	t _{PLZ} , t _{PHZ}	$C_L = 50 pF$	4.5	-	34	43	51	ns
		C _L = 15pF	5	14	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	12	15	18	ns
Input Capacitance	C _{IN}	-	-	-	10	10	10	pF
3-State Capacitance	C _O	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	52	-	-	-	pF

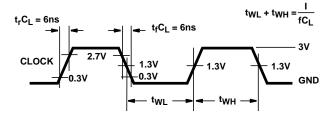
Switching Specifications Input tr, tf = 6n

NOTES:

4. C_{PD} is used to determine the dynamic power consumption, per device.

5. $P_D = V_{CC}^2 (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 2. CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

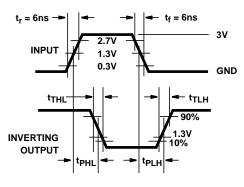
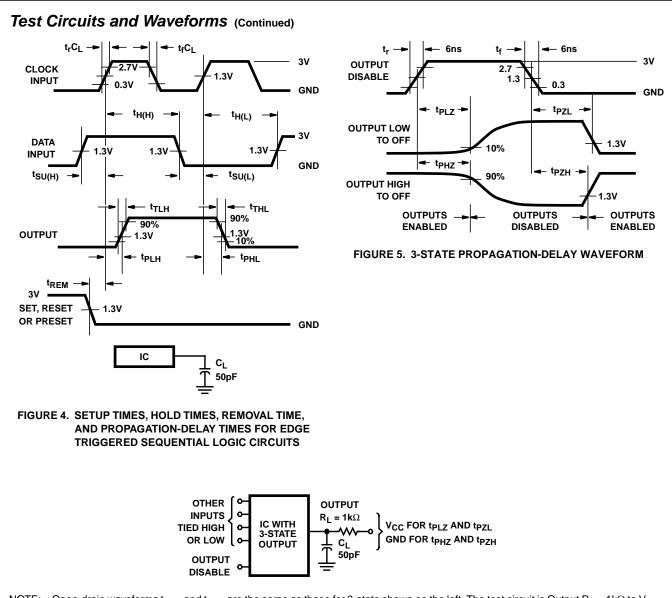


FIGURE 3. TRANSITION TIMES AND PROPAGATION-DELAY TIMES, COMBINATION LOGIC



NOTE: Open-drain waveforms t_{PLZ} and t_{PZL} are the same as those for 3-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 6. 3-STATE PROPAGATION-DELAY TEST CIRCUIT



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT356E	ACTIVE	PDIP	Ν	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT356E	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



www.ti.com

5-Jan-2022

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
CD74HCT356E	N	PDIP	20	20	506	13.97	11230	4.32

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022, Texas Instruments Incorporated